

STPS30M100DJF

Power Schottky rectifier

Features

- Very low conduction losses
- Low forward voltage drop
- Low thermal resistance
- High specified avalanche capability
- High integration
- ECOPACK®2 compliant component

Description

The STPS30M100DJF is a power Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in PowerFLATTM, this device is intended to be used in adaptors requiring good efficiency at both low and high load. Its low profile was especially designed to be used in applications with space-saving constraints.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	30 A
V _{RRM}	100 V
T _j (max)	150 °C
V _F (typ)	0.58 V

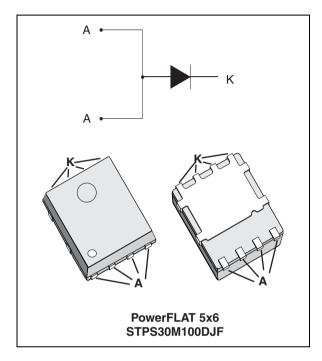
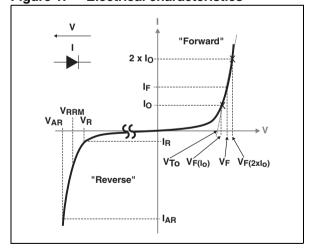


Figure 1. Electrical characteristics (a)



a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 12.* V_{AR} and I_{AR} are pulse measurements ($t_p < 1~\mu s$). V_R , I_R , V_{RRM} and V_F , are static characteristics

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Characteristics

Table 2. Absolute ratings (limiting values, anode terminals short circuited)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage		100	V
I _{F(RMS)}	Forward rms current		45	Α
I _{F(AV)}	Average forward current $\delta = 0.5$	T _c = 90 °C	30	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		200	Α
P _{ARM}	Repetitive peak avalanche power	$t_p = 1 \mu s$, $T_j = 25 °C$	15000	W
V _{ARM} ⁽¹⁾	$ \begin{array}{ll} \text{Maximum repetitive peak avalanche} & t_p < 1 \ \mu\text{s}, \ T_j < 1 \\ \text{voltage} & I_{AR} < 37.5 \ A \end{array} $		120	V
V _{ASM} ⁽¹⁾	Maximum single pulse peak avalanche $$t_p < 1~\mu s, T_j < 150~^{\circ}C$$ voltage $$I_{AR} < 37.5~A$$		120	V
T _{stg}	Storage temperature range	-65 to +175	°C	
T _j	Maximum operating junction temperature	150	°C	

^{1.} Refer to Figure 12.

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case	2.5	°C/W	

Table 4. Static electrical characteristics (anode terminals short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	V - V	-	-	100	μΑ
'R`	current	T _j = 125 °C	$V_R = V_{RRM}$	-	10	40	mA
	V _F ⁽¹⁾ Forward voltage drop	T _j = 25 °C	I _F = 15 A	-	-	0.82	
V _E ⁽¹⁾		T _j = 125 °C		-	0.58	0.66	V
VF. 7 Forward voltage drop	T _j = 25 °C	I _F = 30 A	-	-	0.96	V	
		T _j = 125 °C	1F = 30 A	-	0.66	0.73	

^{1.} Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.65 x $I_{F(AV)}$ + 0.00267 x $I_{F}^{2}_{(RMS)}$

$$P = 0.65 \times I_{F(AV)} + 0.00267 \times I_{F}^{2}_{(RMS)}$$

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 $[\]frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

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Figure 2. Average forward power dissipation Figure 3. Average forward current versus versus average forward current ambient temperature (δ = 0.5)

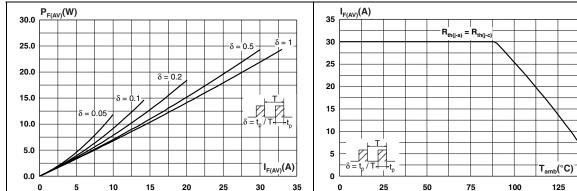


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Normalized avalanche power derating versus junction temperature

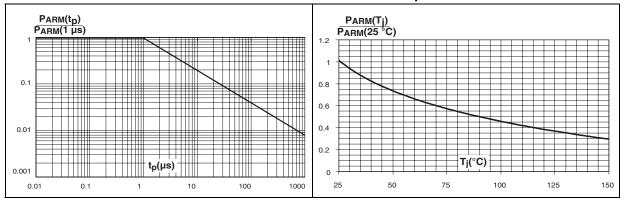
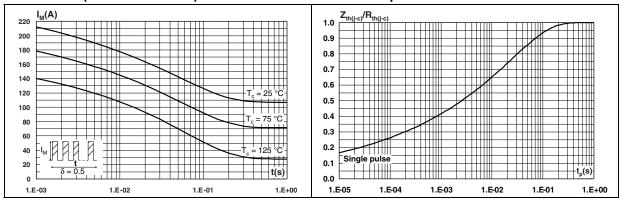


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values)

Figure 7. Relative variation of thermal impedance junction to case versus pulse duration

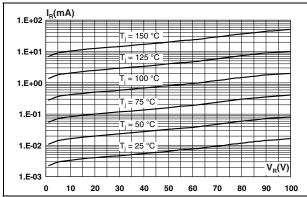


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Figure 8. Reverse leakage current versus reverse voltage applied (typical values)

Figure 9. Junction capacitance versus reverse voltage applied (typical values)



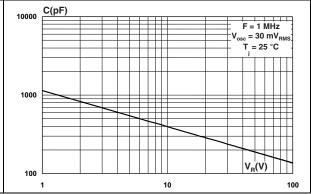
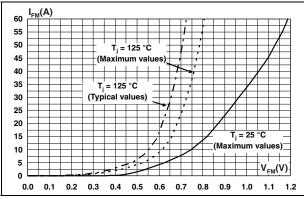


Figure 10. Forward voltage drop versus forward current

Figure 11. Thermal resistance junction to ambient versus copper surface under tab



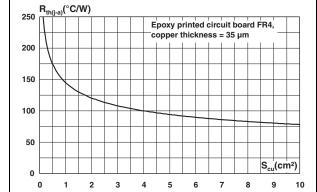
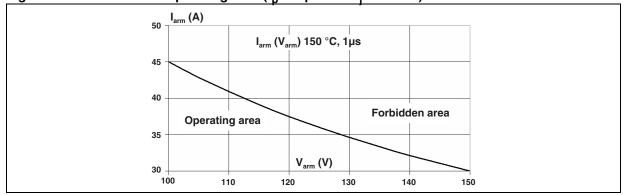


Figure 12. Reverse safe operating area ($t_p < 1 \mu s$ and $T_j < 150 °C$)



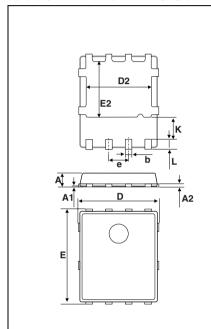
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2 Package information

- Epoxy meets UL94,V0
- Lead-free package

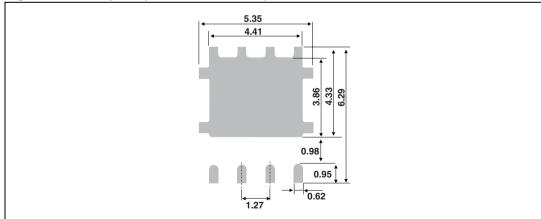
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. PowerFLAT 5x6 dimensions



	Dimensions					
Ref.	M	lillimete	rs		Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.80		1.00	0.031		0.039
A1	0.02		0.05	0.001		0.002
A2		0.25			0.010	
b	0.30		0.50	0.012		0.020
D		5.20			0.205	
D2	4.11		4.31	0.162		0.170
е		1.27			0.050	
Е		6.15			0.242	
E2	3.50		3.70	0.138		0.146
L	0.50		0.80	0.020		0.031
K	1.275		1.575	0.050		0.062

Figure 13. Footprint (dimensions in mm)



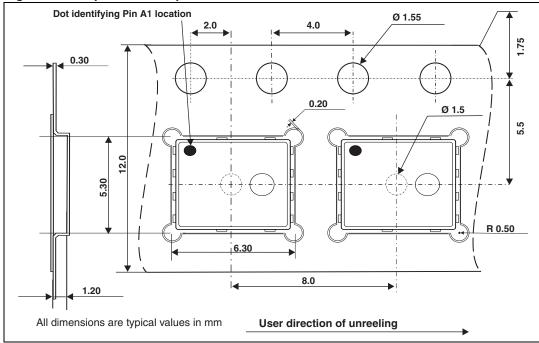


Figure 14. Tape and reel specifications

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight Base qty		Delivery mode	
STPS30M100DJF-TR	PS30 M100	PowerFLAT 5x6	95 mg	3000	Tape and reel	

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
06-Nov-2009	1	First issue.
30-Jul-2010	2	Replace Power QFN with PowerFLAT.
15-Jan-2011	3	Add reference E in <i>Table 5</i> .
20-May-2011	4	Update all package illustrations. Updated base quantity and marking in <i>Table 6</i> . Updated terminal identification in captions of <i>Table 2</i> and <i>Table 4</i> . Added <i>Figure 14</i> .

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